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N-P-N TYPES 2N1302, 2N1304, 2N1306, AND 2N1308 ALLOY-JUNCTION GERMANIUM TRANSISTORS

High-Frequency Transistors for Computer and Switching Applications

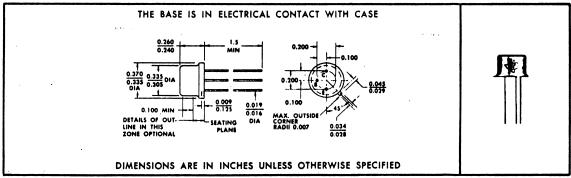
environmental tests

To ensure maximum integrity, stability, and long life, finished devices are subjected to the following tests and conditions prior to thorough testing for rigid adherence to specified characteristics.

- All devices receive a 100°C stabilization bake for 100 hours.
- The hermetic seal for all devices is verified by helium leak testing.
- Production samples are life tested at regularly scheduled periods to ensure maximum reliability under extreme operating conditions.
- Continuous Quality Control checks on in-process assembly are maintained.

*mechanical data

The transistors are in a JEDEC TO-5 hermetically sealed welded package with glass to metal seal between case and leads. Approximate weight is one gram.



*absolute maximum ratings at 25°C free-air temperature (unless otherwise noted)

| in the second | 2N1302, 2N1304 2N1303, 2N1305, 2N1306, 2N1308 2N1307, 2N1309 |
|---|---|
| Collector-Base Voltage | |
| Emitter-Base Voltage | 25 v |
| Collector Current | 🚤300 ma |
| Total Device Dissipation at (or below) 25°C Free-Air Temperature | 150 mw |
| Operating Collector Junction Temperature | |
| Storage Temperature Range | ——— —65°C to 100°C |



Quality Semi-Conductors

TYPES 2N1302, 2N1304, 2N1306, AND 2N1308 N-P-N ALLOY-JUNCTION GERMANIUM TRANSISTORS

electrical characteristics at 25°C free-air temperature

| | PARAMETER | ETER TEST CONDITIONS | | 2N1302 | | | | 2N1304 | 1 | : | 2N1304 | , | : | UNIT | | |
|--------------------|--|------------------------------------|-------------------------|--------|-------------|------|------|-------------|------|------|-------------|----------|------|-------------------------|------|------------|
| | PARAMETER | | | MIN | TYP MAX | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| BYCBO | Collector-Base Breakdown Voltage | I _C = 100 με, | I _E = 0 | 25 | - | - | 25 | - | - | 25 | - | 1 | 25 | - | - | , |
| BVERO | Emitter-Base Breakdown Voltage | $I_g=100~\mu e$, | I _C = 0 | 25 | - | - | 25 | - | _ | 25 | - | - | 25 | - | - | , |
| *V _{PT} | Punch Through Voltage† | V _{EBf1} = 1 v | | 25 | - | - | 20 | - | - | 15 | _ | - | 15 | - | - | ٧ |
| *Icso | Collector Cutoff Current | $V_{CB} = 25 v$ | I _E = 0 | - | 3 | . 6. | - | 3 | 6 | - | 3 | 6 | - | 3 | 6 | μ |
| *IEBO | Emitter Cutoff Current | $V_{EB}=25 v$, | I _C = 0 | - | 2 | 6 | - | 2 | 6 | - | 2 | 6 | - | 2 | 6 | μ |
| *h _{FE} . | Static Forward Current | V _{CE} = 1 v, | I _C = 10 mg | 20 | 100 | - | 40 | 115 | 200 | 60 | 130 | 300 | 80 | 160 | - | T - |
| | Transfer Ratio | V _{CE} = 0.35 v, | I _C = 200 me | 10 | 100 | - | 15 | 110 | _ | 20 | 125 | - | 20 | 140 | - | T - |
| ** | Base-Emitter Voltage | I ₈ = 0.5 ma, | I _C = 10 me | 0.15 | 0.22 | 0.40 | 0.15 | 0.22 | 0.35 | 0.15 | 0.22 | 0.35 | 0.15 | 0.22 | 0.35 | ٧ |
| *YCE(set) | Collector-Emitter Saturation Voltage | I _B = 0.5 ma, | I _C = 10 ms | - | 0.07 | 0.20 | - | - | _ | - | - | _ | - | - | - | • |
| | | 1 ₈ = 0.25 ma, | I _C = 10 me | - | - | Γ- | _ | 0.07 | 0.20 | - | _ | - | - | T- | - | |
| | | I _B = 0.17 ma, | I _C = 10 ms | _ | _ | - | - | _ | _ | - | 0.07 | 0.20 | _ | _ | _ | ľ |
| | | I ₈ = 0.13 ma, | I _C = 10 me | _ | - | _ | _ | _ | _ | - | - | _ | _ | 0.07 | 0.20 | · |
| h _{ib} | Small-Signal Common-Base Input Impedance | $V_{CB} = 5 v,$ $f = 1 kc$ | I _E = -1 ma | - | 28 | - | - | 28 | - | - | 28 | - | - | 28 | - | * |
| h _{rb} | Small-Signal Common-Base Reverse Voltage Transfer Ratio | V _{CB} = 5 v, f = 1 kc | I _E = -1 me | - | 5 x 10-4 | - | _ | 5 x 10-4 | - | - | 5 x 10-4 | - | - | 5 x 10 ⁻⁴ | - | Ι- |
| h _{ob} | Small-Signal Common-Base Output Admittance | $V_{CB} = 5 v$, $f = 1 kc$ | I _E = -1 ma | - | 0.34 | - | - | 0.34 | - | - | 0.34 | - | - | 0.34 | - | μπ |
| hje | Small-Signal Common-Emitter Forward Current Transfer Ratio | V _{CE} = 5 v, f = 1 kc | I _C = 1 ma | - | 105 | - | - | 120 | _ | - | 135 | - | - | 170 | - | <u> </u> |
| *fhfb | Common-Base Alpha- Cutoff Frequency | V _{C8} = 5 v, | I _E = - 1 ma | 3 | 12 | _ | 5 | 14 | - | 10 | 16 | - | 15 | 20 | - | • |
| *(_{ob} | Common-Base Open Circuit Output Capacitance | V _{CB} = 5 v, f = 1 mc | I _E = 0 | | 14 | 20 | - | 14 | 20 | - | 14 | 20 | _ | 14 | 20 | Ŀ |
| Cip | Common-Base Open-Circuit Input Capacitance | V _{EB} = 5 v, f = 1 mc | l _c = 0 | - | 13 | - | - | 13 | - | - | 13 | - | - | 13 | - | Γ, |

 $[\]dagger V_{PT}$ is determined by measuring the emitter-base floating potential V_{EBfl} . The collector-base voltage, V_{CB} , is increased until $V_{EBfl}=1$ volt; this value of $V_{CB}=(V_{PT}+1 \text{ v})$.

switching characteristics at 25°C free-air temperature

| PARAMETER | | TEST CONDITIONS †† | 2N1302 | | | 2N1304 | | | 2N1306 | | | 2N1308 | | | UNIT |
|----------------|--------------------|--|--------|------|-----|--------|------|-----|--------|------|-----|--------|------|-----|------|
| | | | MIN | TYP | MAX | |
| † _d | Delay Time | $I_{\rm C} = 10$ ma, $I_{\rm B(1)} = 1.3$ ma $I_{\rm B(2)} = -0.7$ ma, $Y_{\rm BE~(off)} = -0.8$ v $R_{\rm L} = 1$ k Ω (See Fig. 1) | - | 0.07 | _ | _ | 0.07 | _ | _ | 0.06 | _ | _ | 0.06 | - | μιοι |
| 1, | Rise Time | | - | 0.20 | _ | _ | 0.20 | - | _ | 0.18 | _ | _ | 0.15 | _ | μιος |
| 1, | Storage Time | | _ | 0.70 | - | - | 0.70 | _ | _ | 0.64 | - | _ | 0.64 | - | μια |
| 1, | Fall Time | | - | 0.40 | - | - | 0.40 | - | _ | 0.36 | _ | _ | 0.34 | _ | μιος |
| Qsb | Stored Base Charge | $I_{B(i)} = 1$ ma, $I_C = 10$ ma (See Fig. 2) | - | 800 | - | 1 | 760 | - | _ | 720 | _ | _ | 680 | _ | pcb |

^{††}Veltage and current values shown are nominal; exact values vary slightly with device parameters.

operating characteristics at 25°C free-air temperature

| PARAMETER | TEST CONDITIONS | 2N1302 | | | 2N1304 | | | 2 | N 1 306 | | 2N1308 | | | UNIT |
|----------------------|---|--------|-----|-----|--------|-----|-----|-----|---------|-----|--------|-----|-----|------|
| | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| NF Spot Noise Figure | $V_{CB} = 5 \text{ V}$ $I_B = -1 \text{ me}$ $f = 1 \text{ kc}, \qquad R_G = 1 \text{ k } \Omega$ | 1 | 4 | 1 | ı | • | - | - | 3 | - | - | 3 | - | 4 |